

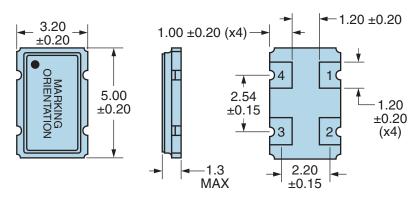
ELECTRICAL SPECIFICATIONS

Operating Shock, an erating Temperature Range -40°C to + oply Voltage 3.3Vdc ±1 ut Current 35mA Max put Voltage Logic High (Voh) 90% of Vc put Voltage Logic Low (Vol) 10% of Vc e/Fall Time 4nSec Max	Aximum (Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Temperature Range, Supply Voltage Change, Ouput Load Change, First Year Aging at 25°C, d Vibration)
pply Voltage 3.3Vdc ±1 ut Current 35mA Max put Voltage Logic High (Voh) 90% of Vc put Voltage Logic Low (Vol) 10% of Vc e/Fall Time 4nSec Max	
ut Current 35mA Max put Voltage Logic High (Voh) 90% of Vo put Voltage Logic Low (Vol) 10% of Vo e/Fall Time 4nSec Max	85°C
put Voltage Logic High (Voh)90% of Voput Voltage Logic Low (Vol)10% of Voe/Fall Time4nSec Ma	0%
put Voltage Logic Low (Vol) 10% of Vol e/Fall Time 4nSec Ma	ximum
e/Fall Time 4nSec Ma	dd Minimum ((IOH = -4mA))
	dd Maximum ((IOL = +4mA))
y Cycle 50 ±10(%)	ximum (Measured at 20% to 80% of waveform)
) (Measured at 50% of waveform)
d Drive Capability 15pF Max	imum
put Logic Type CMOS	
1 Connection Tri-State (High Impedance)
State Input Voltage (Vih and Vil) 90% of Vo Impedanc	d Minimum or No Connect to Enable Output, 10% of Vdd Maximum to Disable Output (High e)
ndby Current 10µA Max	imum (Disabled Output: High Impedance)
S Phase Jitter 1pSec Ma	ximum (12kHz to 20MHz offset frequency)
rt Up Time 10mSec N	<i>I</i> aximum
rage Temperature Range -55°C to +	

ENVIRONMENTAL & MECHANICAL SPECIFICATIONS

ESD Susceptibility	MIL-STD-883, Method 3015, Class 1, HBM: 1500V
Fine Leak Test	MIL-STD-883, Method 1014, Condition A
Flammability	UL94-V0
Gross Leak Test	MIL-STD-883, Method 1014, Condition C
Mechanical Shock	MIL-STD-883, Method 2002, Condition B
Moisture Resistance	MIL-STD-883, Method 1004
Moisture Sensitivity	J-STD-020, MSL 1
Resistance to Soldering Heat	MIL-STD-202, Method 210, Condition K
Resistance to Solvents	MIL-STD-202, Method 215
Solderability	MIL-STD-883, Method 2003
Temperature Cycling	MIL-STD-883, Method 1010, Condition B
Vibration	MIL-STD-883, Method 2007, Condition A

MECHANICAL DIMENSIONS (all dimensions in millimeters)



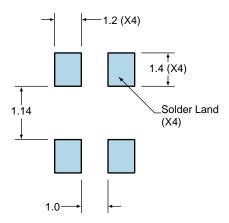
Note: Pin 1 Chamfer not shown.

PIN	CONNECTION
1	Tri-State
2	Ground
3	Output
4	Supply Voltage
LINE	MARKING
LINE	MARKING
LINE 1	MARKING E64.995 E=Ecliptek Designator

ZZ=Week of the Year

Suggested Solder Pad Layout

All Dimensions in Millimeters



All Tolerances are ±0.1

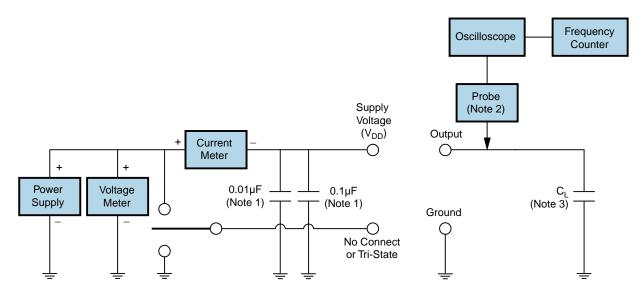




OUTPUT WAVEFORM & TIMING DIAGRAM



Test Circuit for CMOS Output



Note 1: An external 0.1μ F low frequency tantalum bypass capacitor in parallel with a 0.01μ F high frequency ceramic bypass capacitor close to the package ground and V_{DD} pin is required.

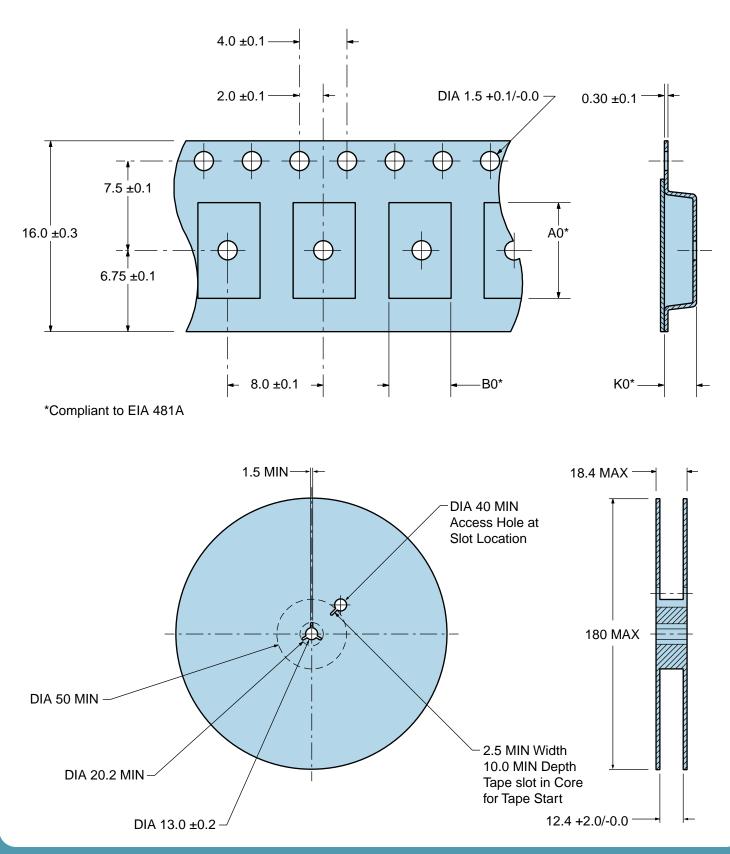
Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.

Note 3: Capacitance value \dot{C}_L includes sum of all probe and fixture capacitance.

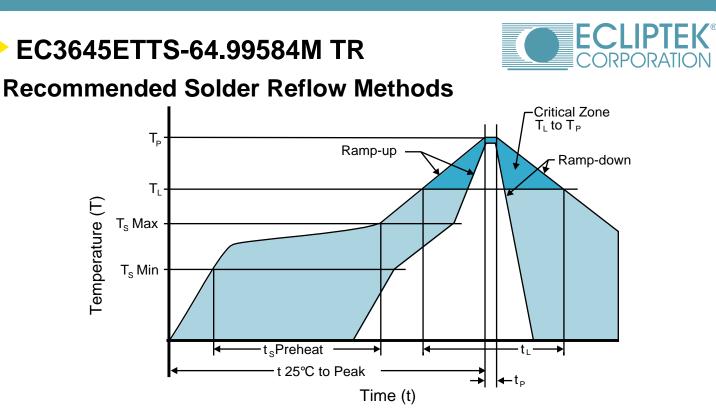


Tape & Reel Dimensions

Quantity Per Reel: 1,000 units

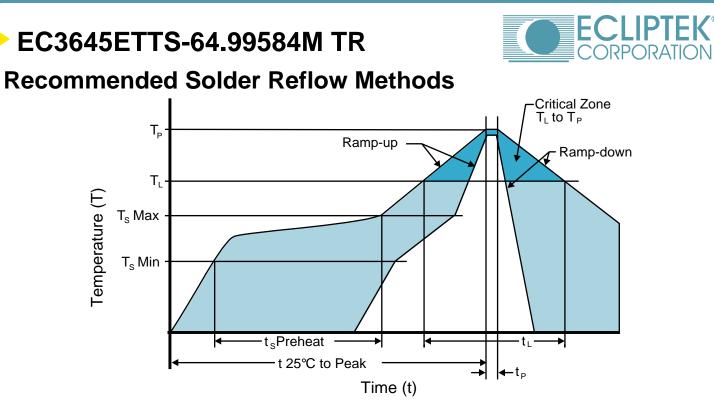


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High Temperature Infrared/Convection

T _s MAX to T _L (Ramp-up Rate)	3°C/second Maximum
Preheat	
- Temperature Minimum (T _s MIN)	150°C
- Temperature Typical (T _s TYP)	175°C
- Temperature Maximum (T _s MAX)	200°C
- Time (t _s MIN)	60 - 180 Seconds
Ramp-up Rate (T _L to T _P)	3°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	217°C
- Time (t∟)	60 - 150 Seconds
Peak Temperature (T _P)	260°C Maximum for 10 Seconds Maximum
Target Peak Temperature (T _P Target)	250°C +0/-5°C
Time within 5°C of actual peak (t _p)	20 - 40 seconds
Ramp-down Rate	6°C/second Maximum
Time 25°C to Peak Temperature (t)	8 minutes Maximum
Moisture Sensitivity Level	Level 1



Low Temperature Infrared/Convection 240°C

T _s MAX to T _L (Ramp-up Rate)	5°C/second Maximum
Preheat	
- Temperature Minimum (Ts MIN)	N/A
- Temperature Typical (T _s TYP)	150°C
• Temperature Maximum (T _s MAX)	N/A
· Time (t _s MIN)	60 - 120 Seconds
Ramp-up Rate (T⊾ to T _P)	5°C/second Maximum
ime Maintained Above:	
Temperature (T∟)	150°C
Time (t∟)	200 Seconds Maximum
Peak Temperature (T _P)	240°C Maximum
arget Peak Temperature (T _P Target)	240°C Maximum 1 Time / 230°C Maximum 2 Times
Fime within 5°C of actual peak (t _ρ)	10 seconds Maximum 2 Times / 80 seconds Maximum 1 Time
Ramp-down Rate	5°C/second Maximum
Time 25°C to Peak Temperature (t)	N/A
Moisture Sensitivity Level	Level 1

Low Temperature Manual Soldering

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

High Temperature Manual Soldering

260°C Maximum for 5 seconds Maximum, 2 times Maximum.